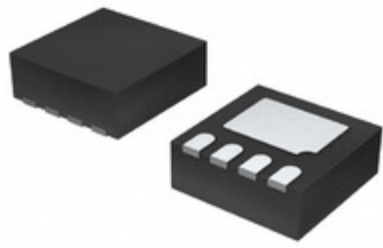


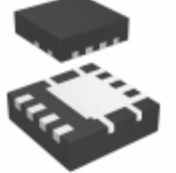



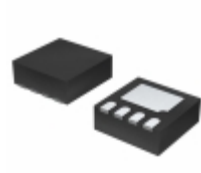
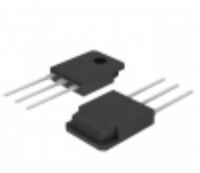

	<h2 style="color: red;">AOV20S60</h2>	
	Hersteller-Teilenummer:	AOV20S60
	Hersteller / Marke:	Alpha and Omega Semiconductor, Inc.
	Teil der Beschreibung:	MOSFET N-CH 600V 18A 5DFB
	Datenblätter:	1.AOV20S60.pdf 2.AOV20S60.pdf
	RoHS Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 53016 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	AOV20S60
Hersteller	Alpha and Omega Semiconductor, Inc.
Beschreibung	MOSFET N-CH 600V 18A 5DFB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	53016 pcs Stock
Serie	aMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	4-VSFN Exposed Pad
Supplier Device-Gehäuse	4-DFN-EP (8x8)
Verlustleistung (max)	8.3W (Ta), 278W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.6A (Ta), 18A (Tc)
Rds On (Max) @ Id, Vgs	250 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	4.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1038pF @ 100V
Verpackung	Tape & Reel (TR)

AOV20S60 ist neu im Original. Suche AOV20S60 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie AOV20S60 Alpha and Omega Semiconductor, Inc. mit Garantie und Vertrauen. Anfrage AOV20S60: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RFD3055LESM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 11A TO-252AA</p>	 <p>DMN3008SFG-7 Diodes Incorporated MOSFET N-CH 30V 17.6A POWERDI</p>	 <p>AOV15S60 Alpha and Omega Semiconductor, Inc. MOSFET N-CH 600V 0.52A 5-DFN</p>	 <p>PHK4NQ10T,518 NXP Semiconductors / Freescale MOSFET N-CH 100V SOT96-1</p>
 <p>AOV27S60 AOS AOS DFN-88</p>	 <p>AOV11S60 Alpha and Omega Semiconductor, Inc. MOSFET N-CH 600V 0.65A 5-DFN</p>	 <p>IXTH280N055T IXYS Corporation MOSFET N-CH 55V 280A TO-247</p>	 <p>FDD8770 Fairchild/ON Semiconductor MOSFET N-CH 25V 35A DPAK</p>

heiße Teile

Mehr

⊕ 02013A2R4CAQ2A	↔ 0402YC223KAT2A	⇒ 08053A332FAT2A	D 12105U5R6BAT2A	↔ 181NQ045R
⊖ 1D1200Z-100E04	⊕ 24LC65T/SM	D 2MBI300L-120	⇒ AC0603JRNPOYBN101	↔ AD9949KCPZRL
⊕ ADM3311EACP-REEL	⊖ ADM4073TWRJZ	⊕ ADS7842E	↔ AON6594D	↔ AOV11S60
D AOV15S60	⊕ BZX584C13-7-F	⊖ CG0402MLC-12LG	⊕ DMP1012UCB9	↔ DS1814CR-10/TR
⇒ FAN5401UCX	↔ GRM1555C1H2R6BA01D	⊕ HLMP-6505-L0011	⊖ ICS9112AM-16T	↔ IRU1010CS
↔ KSE340STU/KSE350	⇒ LAN91C110	D LT1121ACS8-5	⊕ LT1180AISW	⊖ MA1010000L
⊕ MCP3913A1-E/SS	D MDC3105DMT1G	⇒ MK03V73R3BAT2A	↔ MMG100S120UA6TN	↔ MPL73-0R1NV-0807
⊖ MUBW10-12T7	⊕ NCP3064BDR2G	↔ NJM2872BF28	⇒ NTR4502P	↔ P300CH10FJ0
⊕ PE-68887	⊖ PQ1U301M2ZP	⊕ S29GL016D70BF102	D S9S08DZ32F2MLCR	↔ SGH30N60RUFDTU
↔ SY10H842LZI	⊕ TCR5SB25	⊖ TL2217-285PW	⊕ TLC252BCDR	↔ TMPA8873CPANG6HU9

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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